



3-phase Brushless Motor Driver for CD-ROM Spindle Drive Use

Overview

The LB1896 is a 3-phase brushless motor driver IC that is ideal for driving CD-ROM spindle motors.

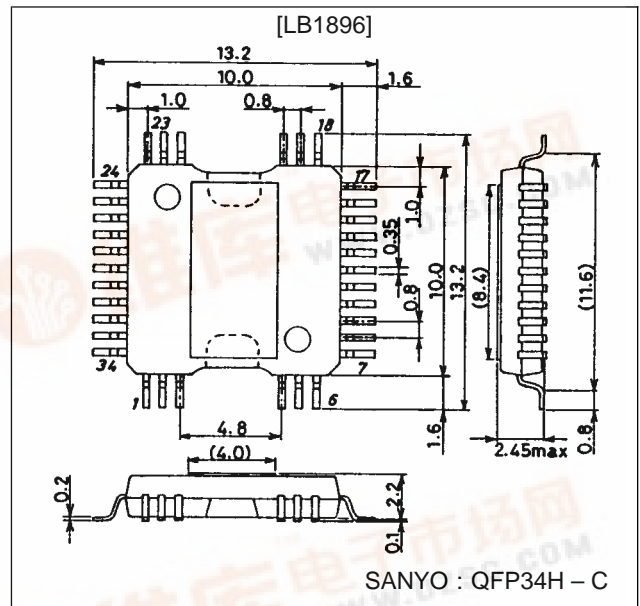
Package Dimensions

unit : mm

3219-QFP34H-C

Functions and Features

- 120° voltage linear technique
- V-type control voltage
- Switchable control gain
- Control, noncontrol, acceleration/deceleration mode select pins built in.
- Start/Stop pin built in, Hall bias built in.



Specifications

Absolute Maximum Ratings at Ta = 25 °C

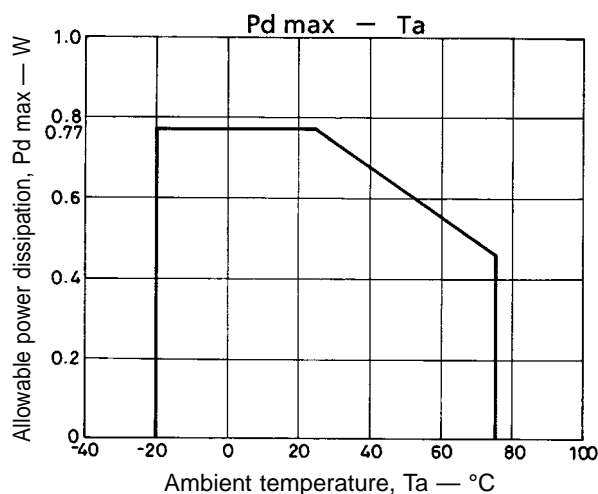
Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC1} max		20	V
	V _{CC2} max		7.0	V
Applied output voltage	V _{OU, V, W}		20	V
Output current	I _{OUT}		1.2	A
Allowable power dissipation	P _d max	Independent IC	0.77	W
Operating temperature	T _{opr}		-20 to +75	°C
Storage temperature	T _{stg}		-55 to +150	°C

Operating Conditions at Ta = 25 °C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{CC1}		5 to 18	V
	V _{CC2}	V _{CC1} ≧ V _{CC2}	4.3 to 6.5	V
V _{Cref} input voltage	V _{Cref}		V _{CC2} /2 ±1.0	V
V _{NS} input voltage	V _{NS}		0 to V _{CC2} -1.0	V



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Electrical Characteristics at Ta = 25 °C, V_{CC1} = 12 V, V_{CC2} = 5 V

Parameter	Symbol	Conditions	min	typ	max	Unit
Supply current 1	I _{CC1}	V _C = open, V _{Cref} = open, R _L = ∞, V _{S/S} = 5 V		17	30	mA
Supply current 2	I _{CC2}	V _C = open, V _{Cref} = open		7.5	10.5	mA
Supply current 3	I _{CC3}	V _C = open, V _{Cref} = open, R _L = ∞, V _{S/S} = 0 V, (I _{CC} of V _{CC1})		0.9	3	mA
[Drive block]						
Output saturation voltage	V _{O(sat)1}	I _{OUT} = 0.4 A, sink + source		1.6	2.2	V
	V _{O(sat)2}	I _{OUT} = 0.8 A, sink + source		2.0	3.0	V
Output TRS sustaining voltage	V _{O(sus)}	I _{OUT} = 20 mA	20			V
Output static voltage	V _{OQ}	V _C = 2.5 V, V _{Cref} = 2.5 V	5.7	6.0	6.3	V
Hall amplifier input offset voltage	V _{H offset}		-5		+5	mV
Hall amplifier input bias current	I _{H bias}			1	5	μA
Hall amplifier common-mode input voltage range	V _{Hch}		1.3		2.2	V
Hall input/output voltage gain	G _{VHO}		40	43	46	dB
Control/output drive gain 1	G _{VCO1}	RZ1 = RZ2, GC1 = L, GC2 = L	26	29		dB
Control/output channel difference 1	ΔG _{VCO1}	RZ1 = RZ2, GC1 = L, GC2 = L	-1.5		+1.5	dB
Control/output drive gain 2	G _{VCO2}	RZ1 = RZ2, GC1 = L, GC2 = H	32	35		dB
Control/output channel difference 2	ΔG _{VCO2}	RZ1 = RZ2, GC1 = L, GC2 = H	-1.9		+1.9	dB
Input dead zone voltage	V _{DZ}	RZ1 = RZ2, GC1 = L, GC2 = L V _O (voltage between out and out) = 0.1 V	±13	±38	±55	mV
Input bias current 1	I _{B SERVO}	V _C = 1.0 V			500	nA
Input bias current 2	I _{B n.s}	V _{NS} = 1.0 V			500	nA
S/S pin high voltage	V _{S/S H}	Input is CMOS level	4			V
S/S pin low voltage	V _{S/S L}	Note) S/S pin V _{th} = V _{CC2} /2			1	V
Gain control 1 high voltage	V _{GC1 H}	Input is at CMOS level.	4			V
Gain control 1 low voltage	V _{GC1 L}	Note) GC1 pin V _{th} = 2.0 V			1	V
Gain control 2 high voltage	V _{GC2 H}	Input is at CMOS level.	4			V
Gain control 2 low voltage	V _{GC2 L}	Note) GC2 pin V _{th} = 2.0 V			1	V
S/S pin input current	I _{S/S}	Input voltage = 5 V		50	100	μA
Gain control 1, 2 current	I _{GC}	Input voltage = 5 V		53	110	μA
Rotation output saturation voltage	V _{(sat) H.FG}	I _O = -5 mA		0.24	0.5	V
Rotation output saturation sustaining voltage	V _{(sus) H.FG}				7	V
Hall bias voltage	V _{H±}	I _O = 5 mA, R _H = 200 Ω	0.7	0.97	1.2	V
CTRL pin high voltage	V _{CTRL H}	Common for CTRL1 and CTRL2 input CMOS level	4			V
CTRL pin low voltage	V _{CTRL L}	Note) CTRL pin V _{th} = 2.5 V			1.0	V
CTRL input current	I _{CTRL}	Input voltage = 5 V		53	110	μA
TSD operation voltage	TSD	Design target	150	180	210	°C
TSD hysteresis	ΔTSD	Design target		15		°C

Note) V_{th} is a design target and not measured.

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Mode Switching Truth Table

CTRL0	CTRL1	Mode
L	L	Control
L	H	Noncontrol
H	L	Acceleration
H	H	Deceleration

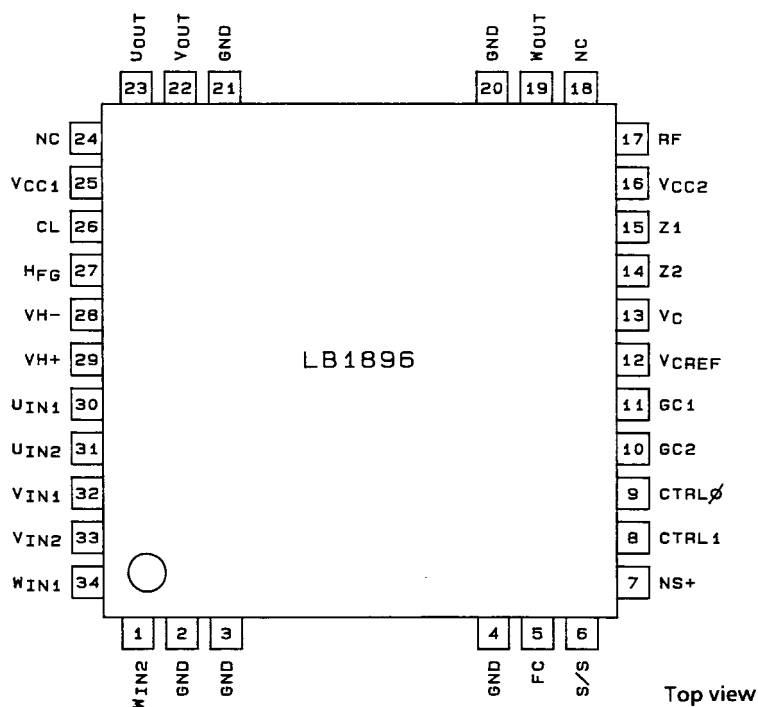
L = 0 to 1.0 V
H = 4.0 V or more

Hall Logic Truth Table

	Source → Sink	Hall input			F/R Control
		U _{IN}	V _{IN}	W _{IN}	
1	W → V	H	H	L	Forward
	V → W				Reverse
2	W → U	H	L	L	Forward
	U → W				Reverse
3	V → W	L	L	H	Forward
	W → V				Reverse
4	U → V	L	H	L	Forward
	V → U				Reverse
5	V → U	H	L	H	Forward
	U → V				Reverse
6	U → W	L	H	H	Forward
	W → U				Reverse

An input is considered to be HIGH when $U_{IN1} > U_{IN2}$, $V_{IN1} > V_{IN2}$, and $W_{IN1} > W_{IN2}$ by 0.2 V or more.
Forward when $V_C > V_{Cref}$
Reverse when $V_C < V_{Cref}$

Pin Assignment



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Pin Functions

Pin No.	Pin Name	Pin Voltage	Equivalent Circuit Diagram	Pin Function
3, 4 20, 21	Frame GND			Frame GND. GND must be shared.
2	GND			GND
23 22 19	U_{OUT} V_{OUT} W_{OUT}		<p style="text-align: right;">A04490</p>	Output pins. Motor connection
17	Rf		<p style="text-align: right;">A04491</p>	Output Tr GND. A resistor can be connected between this pin and GND to sense the output current as a voltage drop to provide for overcurrent protection.
18, 24	NC			Idle pins.
16	V_{CC2}	4.3 to 6.5 V		<ul style="list-style-type: none"> Power supply for blocks other than the output block. This supply should be kept stable to prevent ripple and noise from entering this pin.
15 14	Z1 Z2		<p style="text-align: right;">A04492</p>	<ul style="list-style-type: none"> First-stage amplifier gain setting resistors. Z1 and Z2 normally range from several tens of kΩ to several hundreds of kΩ. The gain is about 6 dB.
13 12	V_C V_{Cref}	$V_{CC2}/2 \pm 1.0$	<p style="text-align: right;">A04493</p>	<ul style="list-style-type: none"> V_C is the speed control pin. Forward when $V_C > V_{Cref}$. Reverse when $V_C < V_{Cref}$. V_C is used to control the output voltage. V_{Cref} determines the motor control stop voltage. $V_{CC2}/2$ in normal use.
11 10	GC1 GC2	0 to V_{CC2}	<p style="text-align: right;">A04494</p>	<ul style="list-style-type: none"> Input/output gain switching pins. GC1 is for first-stage amplifier Z1/Z2 switching. When GC1 is LOW, Z1 is selected; when HIGH, Z2 is selected. GC2 is for next-stage amplifier switching.

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Pin No.	Pin Name	Pin Voltage	Equivalent Circuit Diagram	Pin Function
9 8	CTRL ϕ CTRL1	0 to V _{CC2}	<p style="text-align: right;">A04495</p>	<ul style="list-style-type: none"> Operation mode switching pins. Refer to the Mode Switching Truth Table for selection of control, acceleration, or deceleration.
7	NS+	0 to V _{CC2} - 1 V	<p style="text-align: right;">A04496</p>	<ul style="list-style-type: none"> Input pin at noncontrol mode. The input-output gain is 14 dB. (GC2: LOW) Motor stops when V_{NS} = 0 V.
6	S/S	0 to V _{CC2}	<p style="text-align: right;">A04497</p>	<ul style="list-style-type: none"> When the S/S pin is HIGH, START; when LOW, STOP. The threshold is V_{CC2}/2.
5	FC		<p style="text-align: right;">A04498</p>	<ul style="list-style-type: none"> Connect a capacitor between this pin and GND to reduce the input/output gain frequency response and to stop the oscillator.
1 34 33 32 31 30	W _{IN2} W _{IN1} V _{IN2} V _{IN1} U _{IN2} U _{IN1}	1.3 to 2.2 V	<p style="text-align: right;">A04499</p>	<p>W-phase Hall device input pins. Logic "H" represent W_{IN1} > W_{IN2} V-phase Hall device input pins. Logic "H" represent V_{IN1} > V_{IN2} U-phase Hall device input pins. Logic "H" represent U_{IN1} > U_{IN2}</p>

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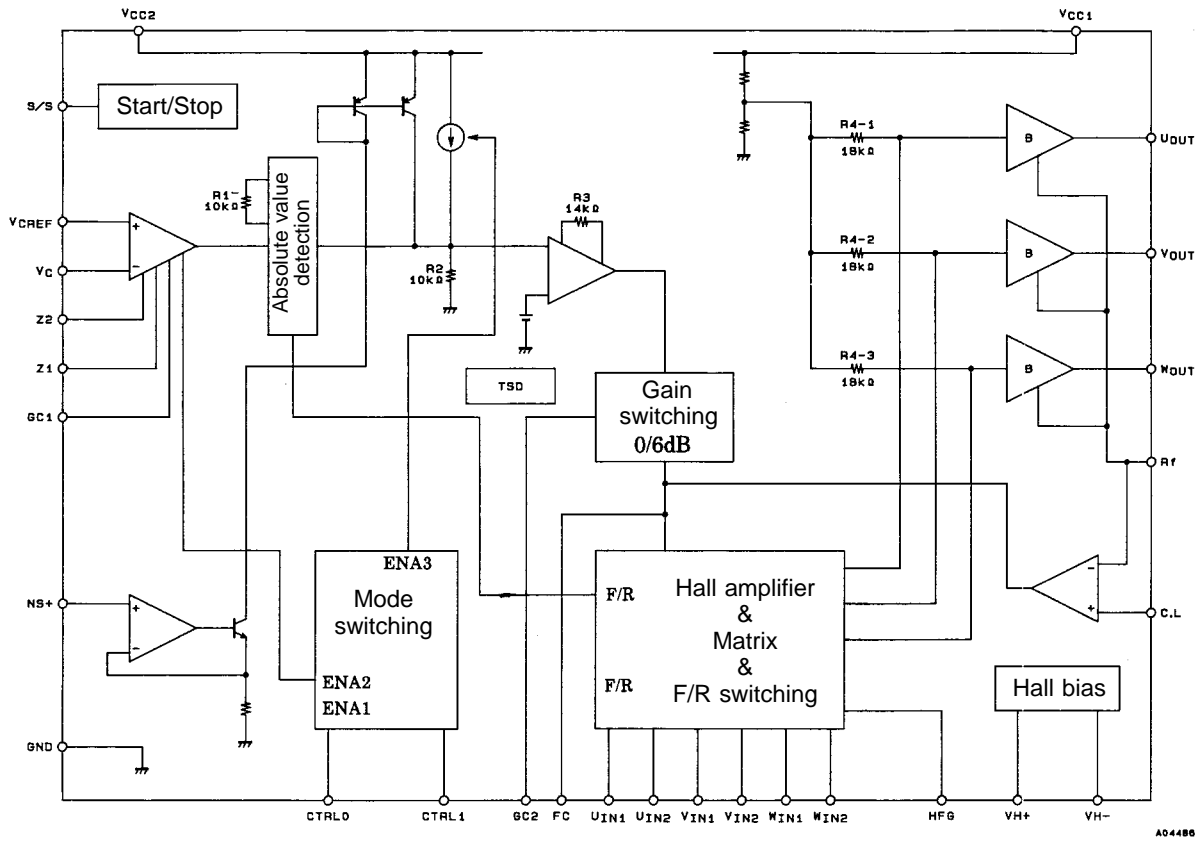
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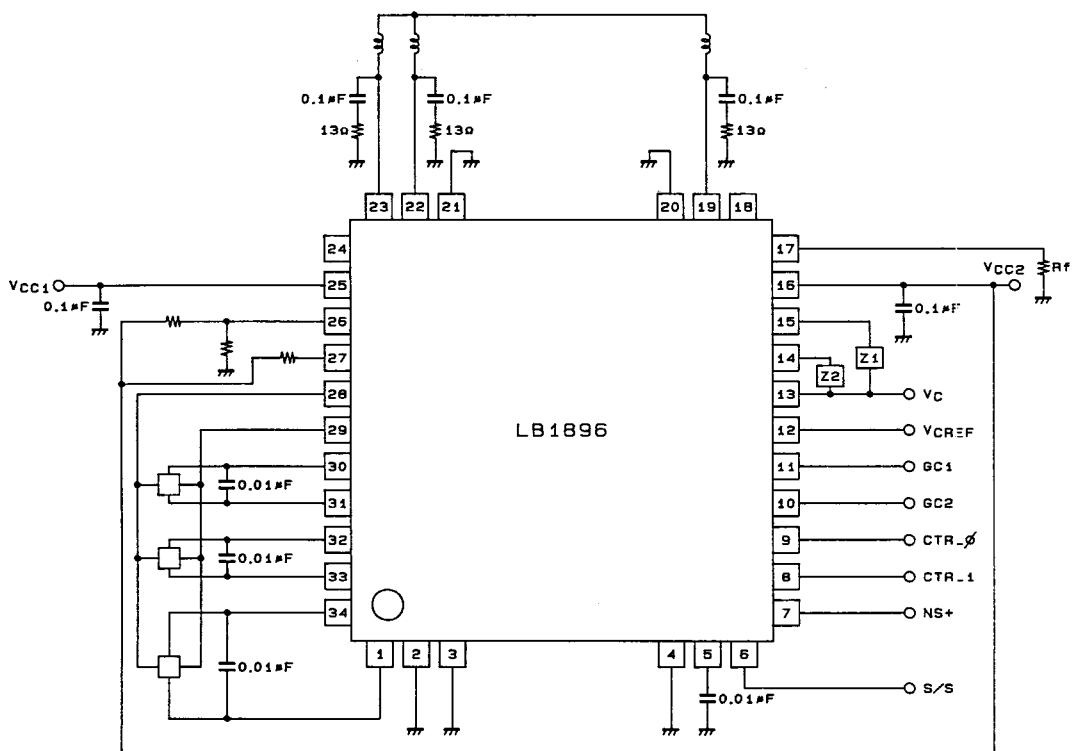
Pin No.	Pin Name	Pin Voltage	Equivalent Circuit Diagram	Pin Function
29 28	VH+ VH-	2.4 V 1.4 V		<ul style="list-style-type: none"> Hall device power supply pins. A voltage difference of 1.0 V is developed between VH+ and VH-.
27	H.FG	0 to V _{CC2}		<ul style="list-style-type: none"> Hall FG pin. The Hall waveform is converted into a pulse signal and then used as the FG pulse signal.
26	CL	0 to V _{CC2}		<ul style="list-style-type: none"> When the R_f pin voltage becomes equal to the C_L pin voltage, the current limiter operate. The C_L voltage is determined externally.
25	V _{CC1}	5 to 18 V		<ul style="list-style-type: none"> Power supply for output block. This supply should be kept stable to prevent ripple and noise from entering this pin.

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Block Diagram



Sample Application Circuit



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